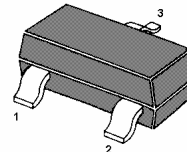


# BC846 ... BC850

## NPN Silicon Epitaxial Transistor

for switching and amplifier applications

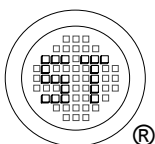
As complementary types the PNP transistors BC856...BC860 is recommended.



1. Base 2. Emitter 3. Collector  
SOT-23 Plastic Package

### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Units
Collector Base Voltage	BC846 $V_{CBO}$	80	V
	BC847, BC850 $V_{CBO}$	50	V
	BC848, BC849 $V_{CBO}$	30	V
Collector Emitter Voltage	BC846 $V_{CEO}$	65	V
	BC847, BC850 $V_{CEO}$	45	V
	BC848, BC849 $V_{CEO}$	30	V
Emitter Base Voltage	BC846, BC847 $V_{EBO}$	6	V
	BC848, BC849, BC850 $V_{EBO}$	5	V
Collector Current	$I_C$	100	mA
Peak Collector Current	$I_{CM}$	200	mA
Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature Range	$T_S$	- 65 to + 150	$^\circ\text{C}$



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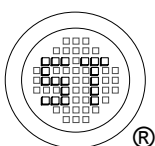


Dated : 21/06/2006

# BC846 ... BC850

## Characteristics at $T_{amb} = 25\text{ }^{\circ}\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Units		
DC Current Gain at $V_{CE} = 5\text{ V}$ , $I_C = 2\text{ mA}$	A	$h_{FE}$	110	-	220	-	
	B	$h_{FE}$	200	-	450	-	
	C	$h_{FE}$	420	-	800	-	
Collector Emitter Saturation Voltage at $I_C = 10\text{ mA}$ , $I_B = 0.5\text{ mA}$ at $I_C = 100\text{ mA}$ , $I_B = 5\text{ mA}$	$V_{CEsat}$	-	-	250	mV		
	$V_{CEsat}$	-	-	600	mV		
Base Emitter On Voltage at $I_C = 2\text{ mA}$ , $V_{CE} = 5\text{ V}$ at $I_C = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$	$V_{BE(on)}$	580	-	700	mV		
	$V_{BE(on)}$	-	-	720	mV		
Collector Cutoff Current at $V_{CB} = 30\text{ V}$	$I_{CBO}$	-	-	15	nA		
Current Gain Bandwidth Product at $V_{CE} = 5\text{ V}$ , $I_C = 10\text{ mA}$ , $f = 100\text{ MHz}$	$f_T$	-	300	-	MHz		
Output Capacitance at $V_{CB} = 10\text{ V}$ , $f = 1\text{ MHz}$	$C_{ob}$	-	-	6	pF		
Input Capacitance at $V_{EB} = 0.5\text{ V}$ , $f = 1\text{ MHz}$	$C_{ib}$	-	9	-	pF		
Noise Figure at $I_C = 200\text{ }\mu\text{A}$ , $V_{CE} = 5\text{ V}$ , $R_G = 2\text{ K}\Omega$ , $f = 1\text{ KHz}$	BC846, BC847, BC848	NF	-	-	10	dB	
	BC849, BC850	NF	-	-	4	dB	
	at $I_C = 200\text{ }\mu\text{A}$ , $V_{CE} = 5\text{ V}$ , $R_G = 2\text{ K}\Omega$ , $f = 30 \sim 15\text{ KHz}$	BC849	NF	-	-	4	dB
		BC850	NF	-	-	3	dB



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ISO/TS 16949 : 2002  
Certificate No. 05103



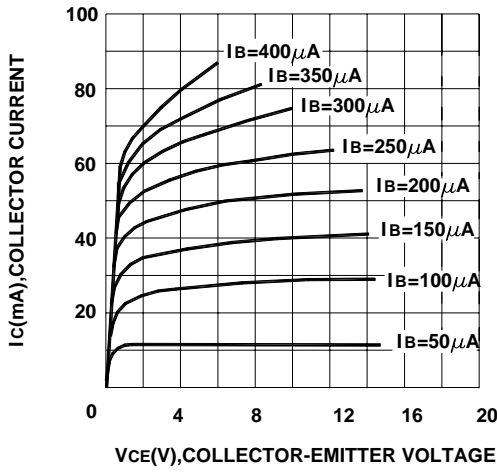
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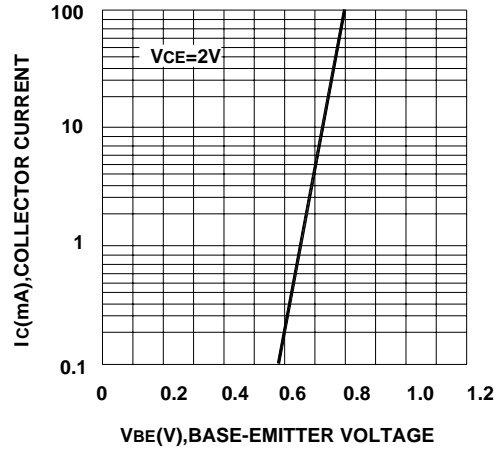
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Dated : 21/06/2006

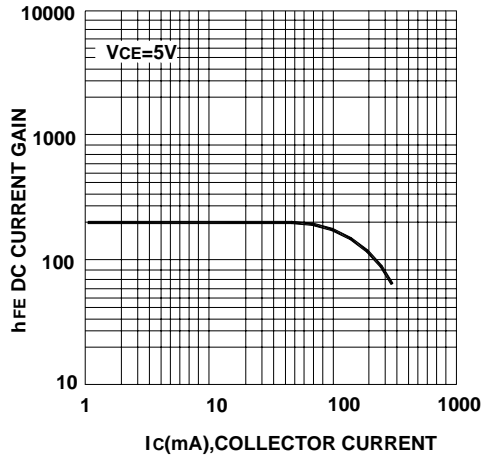
STATIC CHARACTERISTIC



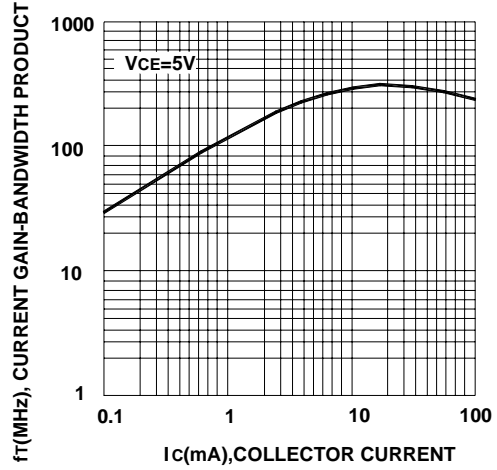
BASE-EMITTER ON VOLTAGE



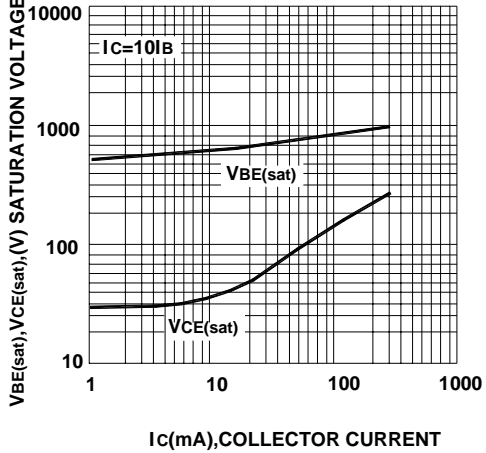
DC CURRENT GAIN



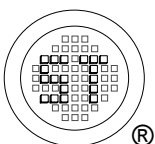
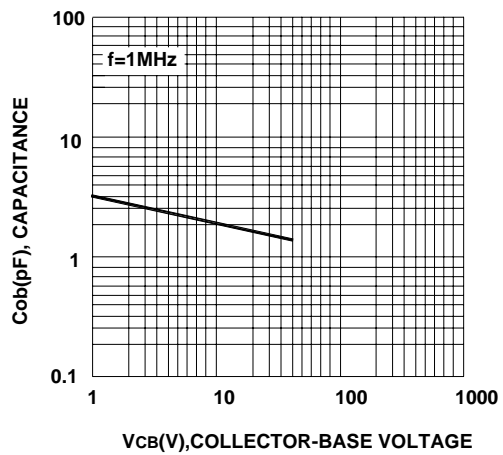
CURRENT GAIN BANDWIDTH PRODUCT



BASE-EMITTER SATURATION VOLTAGE  
COLLECTOR-EMITTER SATURATION VOLTAGE



COLLECTOR OUTPUT CAPACITANCE



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Certificate No. 71116



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Certificate No. 0506098